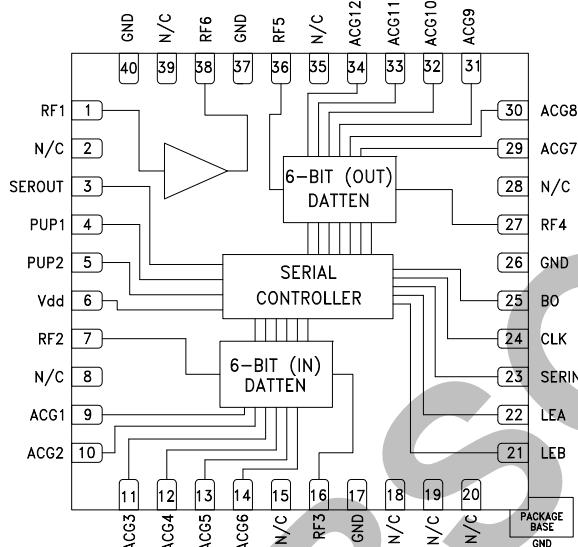


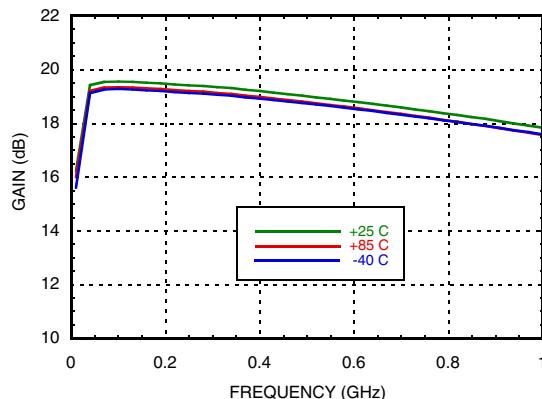
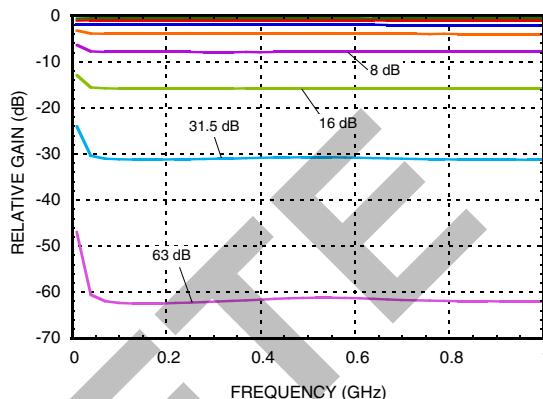
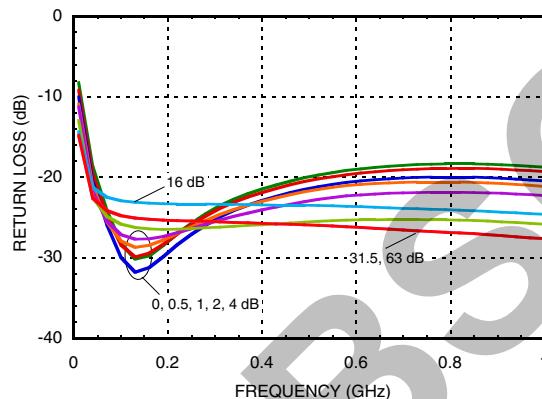
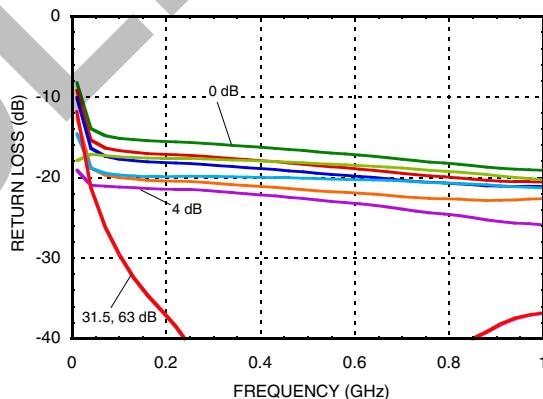
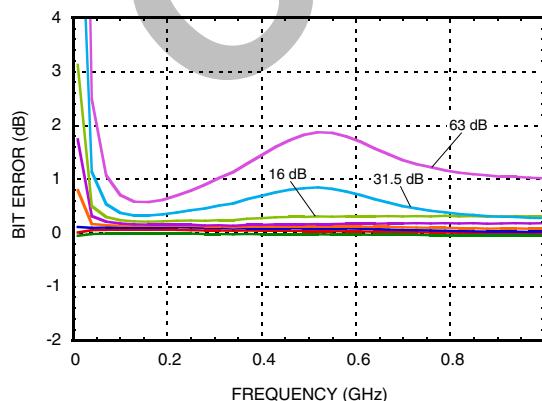
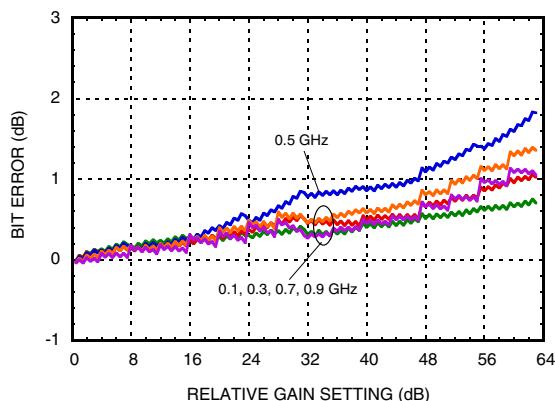

**0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz**
**Typical Applications**

The HMC743ALP6CE is ideal for:

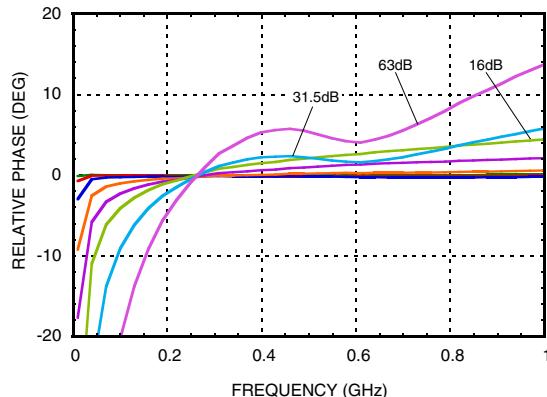
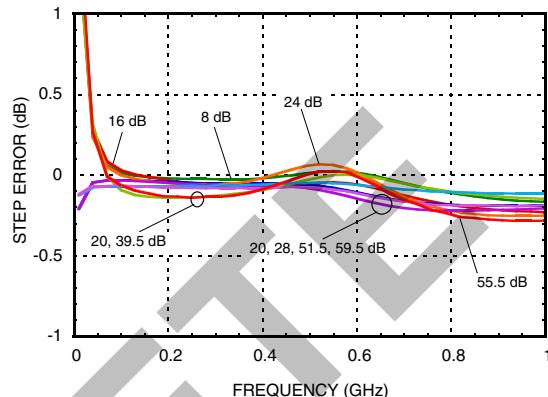
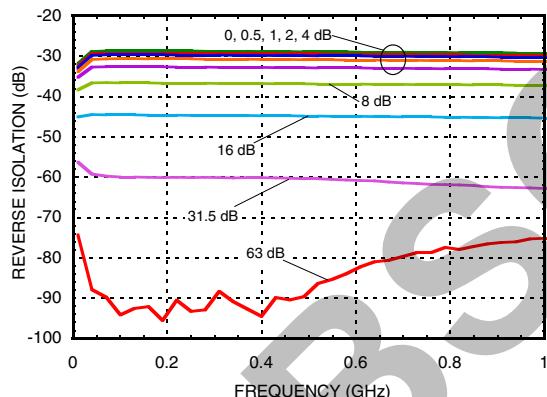
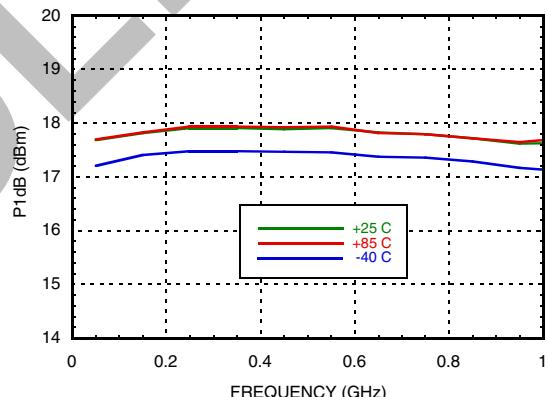
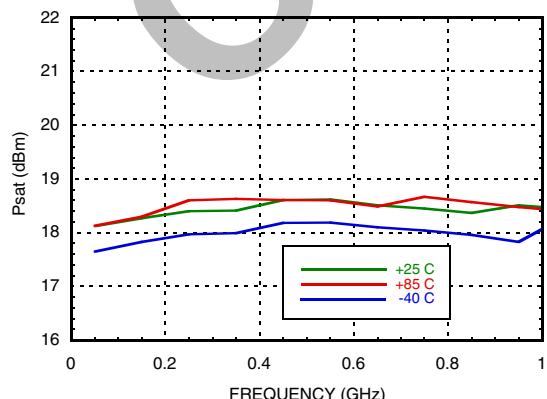
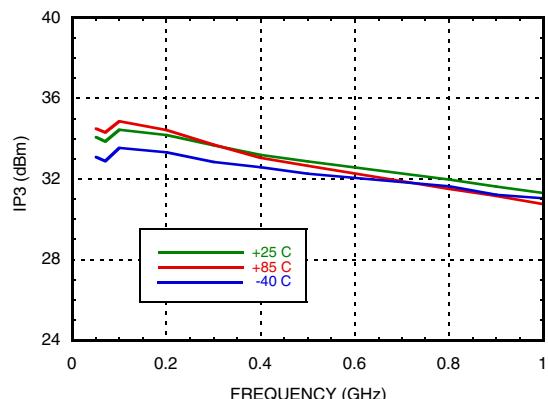
- Cellular/3G Infrastructure
- WiBro, WiMAX & LTE/4G
- Microwave Radio & VSAT
- Test Equipment and Sensors
- IF & RF Applications

**Functional Diagram**

**Electrical Specifications,  $T_A = +25^\circ C$ , 50 Ohm System  $Vdd = +5V$ ,  $Vcc = +5V$** 

| Parameter  | Min.   | Typ. | Max.   | Min.       | Typ. | Max. | Units          |
|--|--|------|--|------------|------|------|----------------|
| Frequency Range  | 70 - 1000  |      |  | 700 - 4000 |      |      | MHz            |
| Gain (Maximum Gain State)  | 15.5   | 18.5 |  | 6          | 13   |      | dB             |
| Gain Control Range   |  | 63   |  |            | 63   |      | dB             |
| Input Return Loss  |  | 18   |  |            | 19   |      |                |
| Output Return Loss   |  | 15   |  |            | 17   |      | dB             |
| Gain Accuracy: (Referenced to Maximum Gain State)<br>All Gain States           | 70 - 350 MHz: $\pm (0.3 + 3.5\%)$<br>350 - 750 MHz: $\pm (0.3 + 5.0\%)$<br>750 - 1000 MHz: $\pm (0.3 + 4.0\%)$ |      | 0.7 - 1.7 GHz: $\pm (0.3 + 4.5\%)$<br>1.7 - 3.2 GHz: $\pm (0.3 + 4.0\%)$<br>3.2 - 4.0 GHz: $\pm (0.3 + 5.0\%)$ |            |      |      | dB<br>dB<br>dB |
| Output Power for 1 dB Compression  |  | 17.5 |  |            | 17   |      | dBm            |
| Output Third Order Intercept Point<br>(Two-Tone Output Power= 8 dBm Each Tone) |  | 33   |  |            | 28   |      | dBm            |
| Noise Figure   |  | 6    |  |            | 7    |      | dB             |
| Switching Characteristics  |  |      |  |            |      |      |                |
| tRISE, tFall (10 / 90% RF)   |  | 100  |  |            | 100  |      | ns             |
| tON, tOFF (Latch Enable to 10 / 90% RF)  |  | 160  |  |            | 160  |      | ns             |
| Supply Current (Idd)   |  | 5    |  |            | 5    |      | mA             |
| Supply Current (Icc)   |  | 82   | 102  |            | 82   | 102  | mA             |

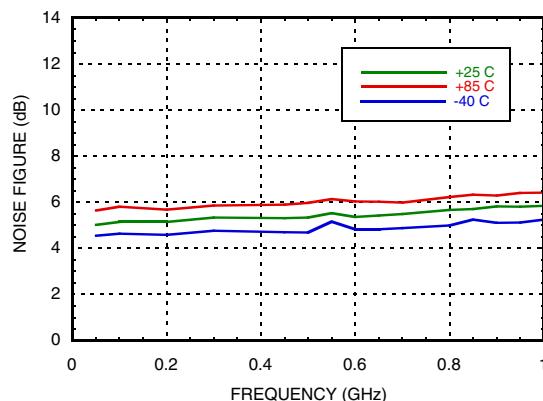
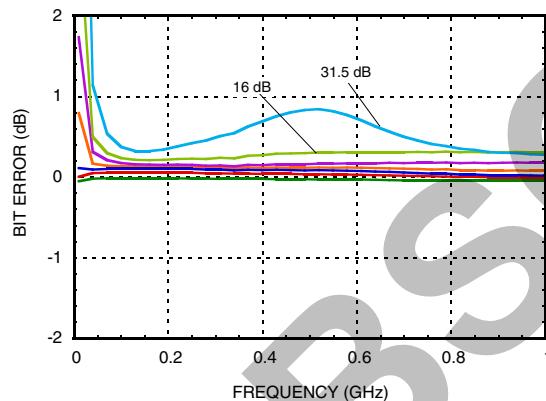
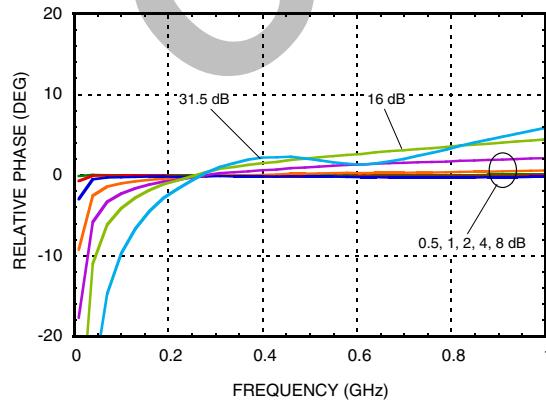
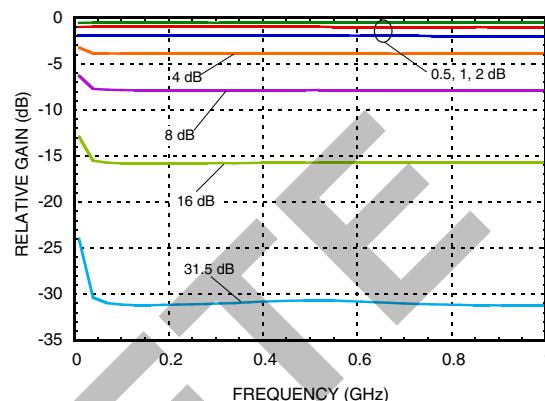
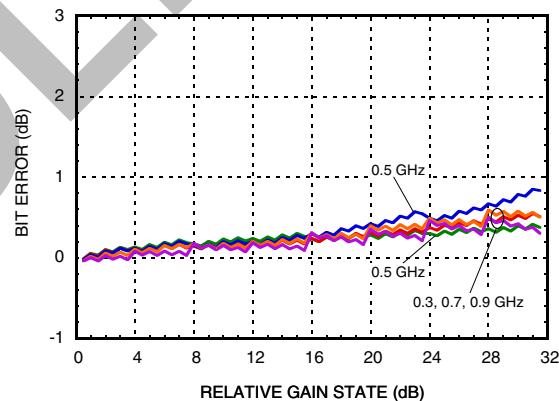
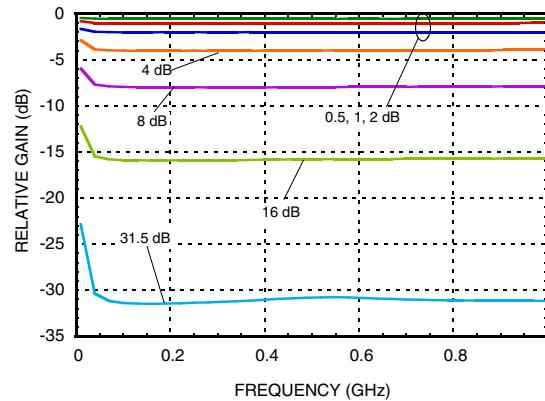

**0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz**
**70 to 1000 MHz Tuning**
**Maximum Gain vs. Temperature**

**Relative Gain Setting [1]**
*(Referenced to Maximum Gain State)*

**Input Return Loss [1]**

**Output Return Loss [1]**

**Bit Error vs. Frequency [1]**

**Bit Error vs. Relative Gain State [1]**
*(Major Frequencies)*


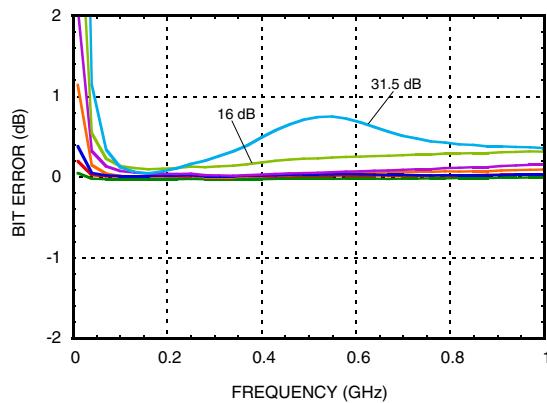
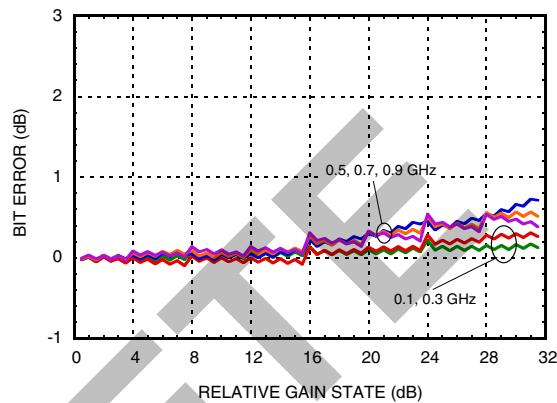
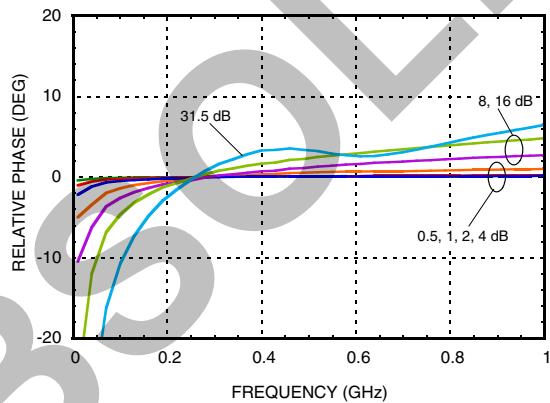
[1] Input Attenuator swept for 0 - 31.5 dB States and Output Attenuator swept for 32 - 63 dB States


**0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz**
**70 to 1000 MHz Tuning**
**Relative Phase vs. Frequency [1]**

**Step Error vs. Frequency [1] (Worst Case)**

**Reverse Isolation [1] (Major States)**

**Output P1dB vs. Temperature [2]**

**Psat vs. Temperature [2]**

**Output IP3 vs. Temperature [2]**


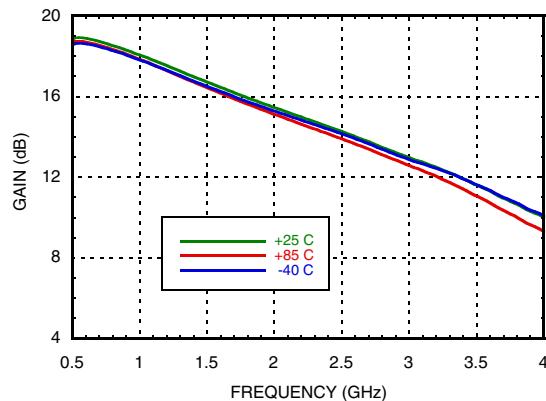
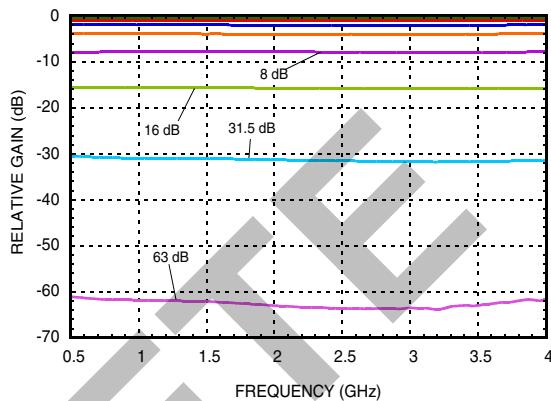
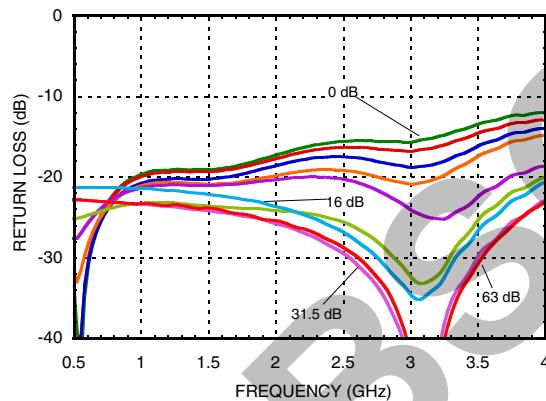
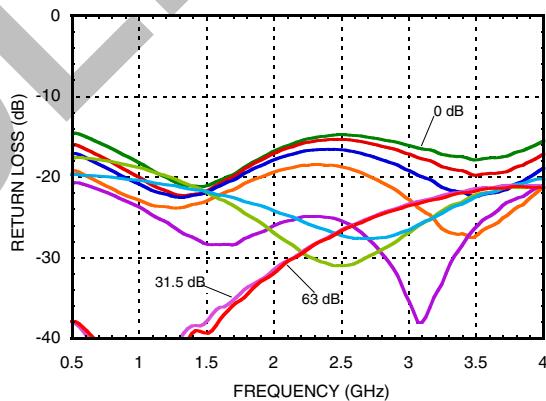
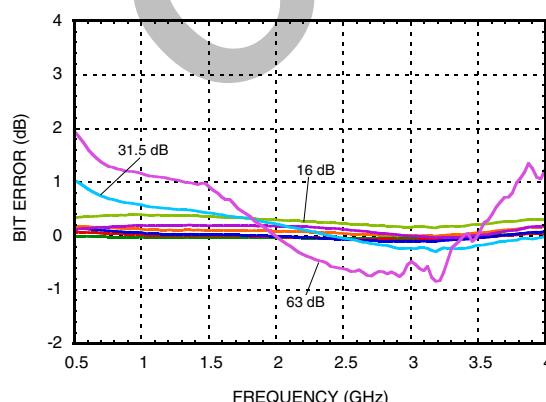
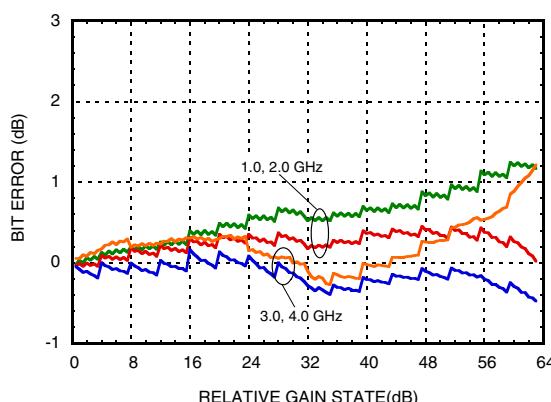
[1] Input Attenuator swept for 0 - 31.5 dB States and Output Attenuator swept for 32 - 63 dB States

[2] Max Gain State


**0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz**
**70 to 1000 MHz Tuning**
**Noise Figure vs. Frequency [2]**

**Input Attenuator Bit Error vs. Frequency [3] (Major States)**

**Input Attenuator Relative Phase vs. Frequency [3] (Major States)**

**[2] Max Gain State**
**[3] Output Attenuator set to 0 dB State**
**Input Attenuator Relative Attenuation [3] (Major States)**

**Input Attenuator Bit Error vs. Attenuation State [3] (Major Frequencies)**

**Output Attenuator Relative Attenuation [4] (Major States)**

**[4] Input Attenuator set to 0 dB State**


**0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz**
**70 to 1000 MHz Tuning**
**Output Attenuator Bit Error vs.  
Frequency [4] (Major States)**

**Output Attenuator Bit Error vs.  
Attenuation State [4] (Major Frequencies)**

**Output Attenuator Relative Phase vs.  
Frequency [4] (Major States)**


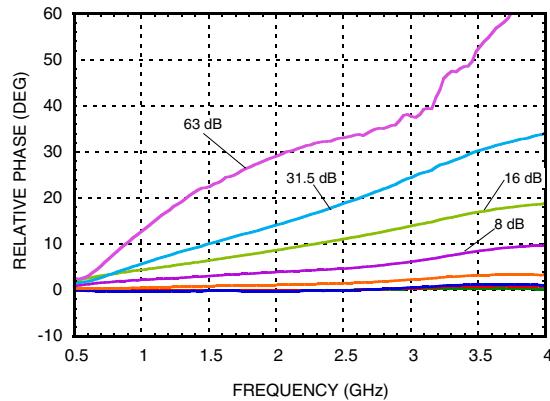
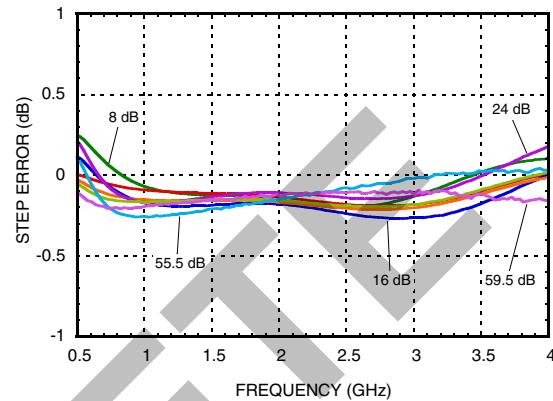
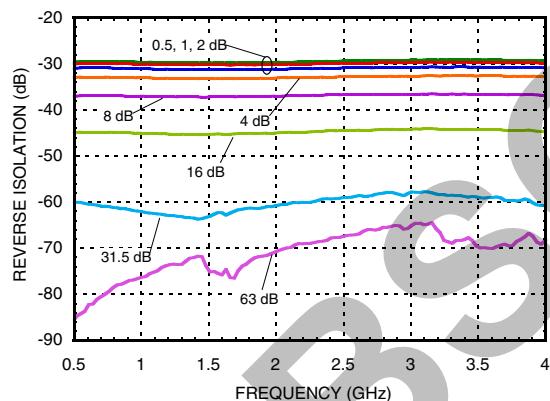
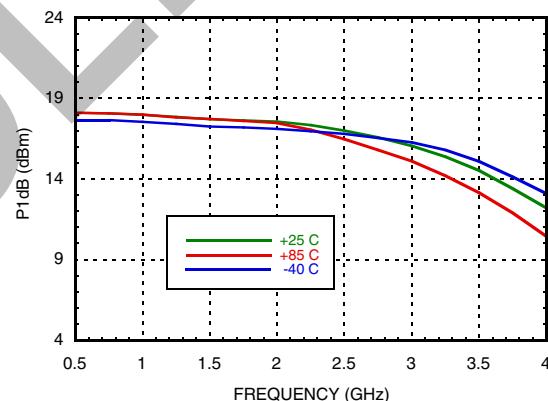
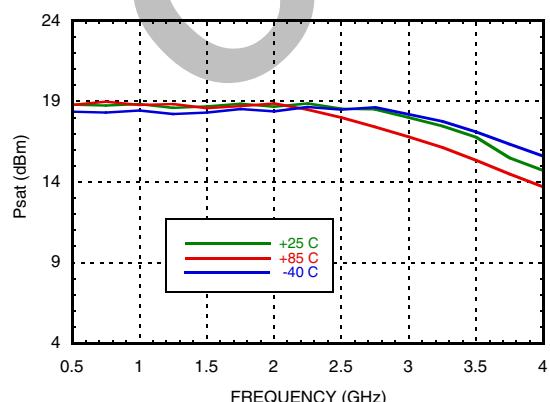
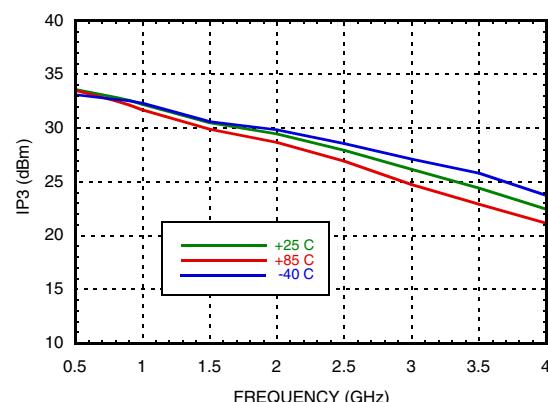
[4] Input Attenuator set at 0 dB State


**0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz**
**0.7 to 4.0 GHz Tuning**
**Maximum Gain vs. Temperature**

**Relative Gain Setting [1]**
*(Referenced to Maximum Gain State)*

**Input Return Loss [1]**

**Output Return Loss [1]**

**Bit Error vs. Frequency [1]**

**Bit Error vs. Relative Gain State [1]**
*(Major Frequencies)*


[1] Input Attenuator swept for 0 - 31.5 dB States and Output Attenuator swept for 32 - 63 dB States

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**0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz**
**0.7 to 4.0 GHz Tuning**
**Relative Phase vs. Frequency [1]**

**Step Error vs. Frequency (Worst Case) [1]**

**Reverse Isolation [1]**

**Output P1dB vs. Temperature [2]**

**Psat vs. Temperature [2]**

**Output IP3 vs. Temperature [2]**


[1] Input Attenuator swept for 0 - 31.5 dB States and Output Attenuator swept for 32 - 63 dB States

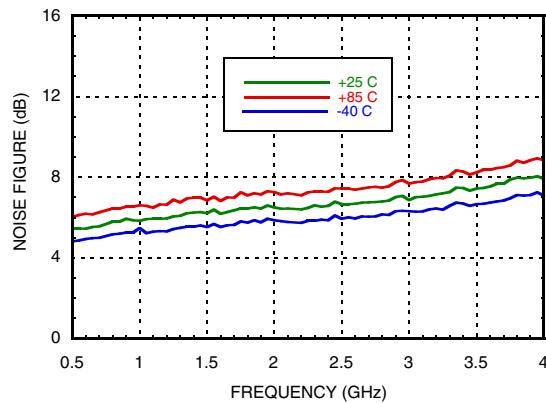
[2] Max Gain State



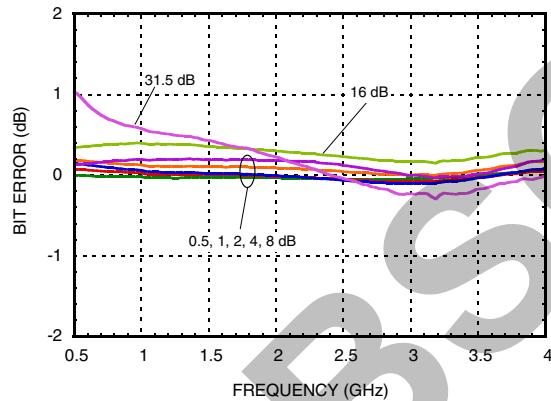
## 0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz

0.7 to 4.0 GHz Tuning

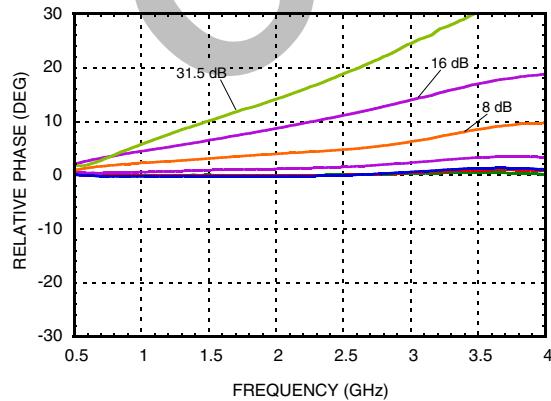
### Noise Figure vs. Frequency [2]



### Input Attenuator Bit Error vs. Frequency [3] (Major States)



### Input Attenuator Relative Phase vs. Frequency [3] (Major States)

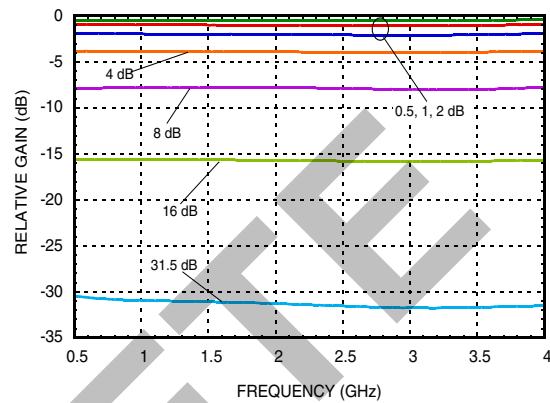


[2] Max Gain State

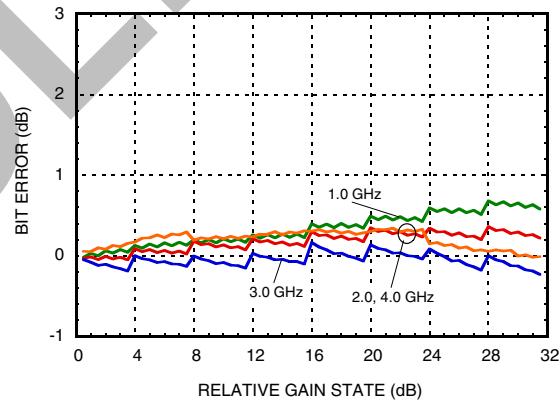
[3] Output Attenuator set to 0 dB Stat

### Input Attenuator Relative Attenuation [3] (Major States)

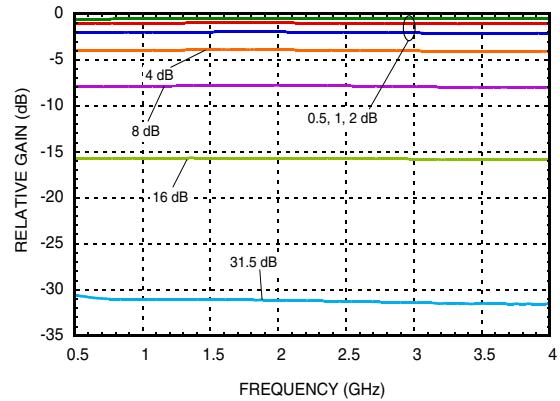
(Major States)



### Input Attenuator Bit Error vs. Attenuation State [3] (Major Frequencies)



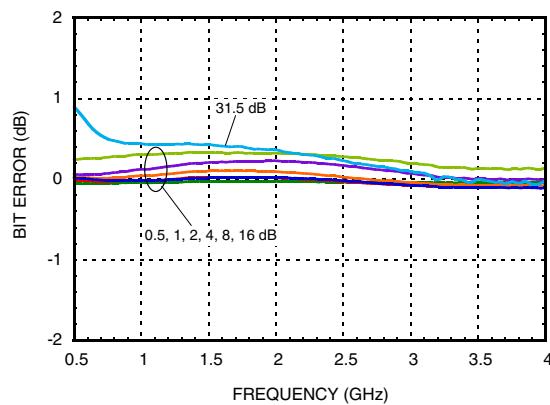
### Output Attenuator Relative Attenuation [4] (Major Steps)



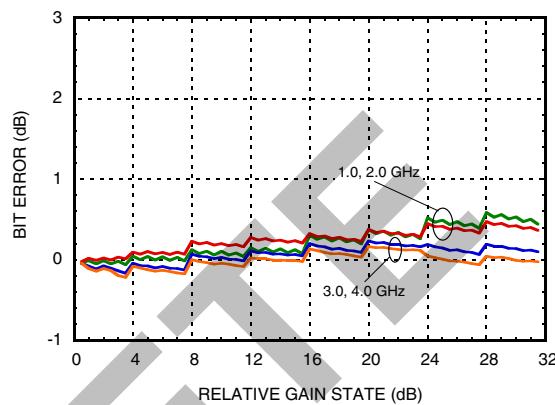
[4] Input Attenuator set to 0 dB State


**0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL  
VARIABLE GAIN AMPLIFIER, DC - 4 GHz**
**0.7 to 4.0 GHz Tuning**

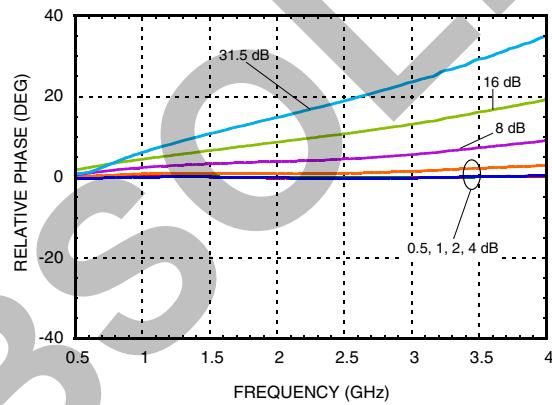
**Output Attenuator Bit Error vs.  
Frequency [4] (Major States)**



**Output Attenuator Bit Error vs.  
Attenuation State [4] (Major Frequencies)**



**Output Attenuator Relative Phase vs.  
Frequency [4] (Major States)**



[4] Input Attenuator set at 0 dB State



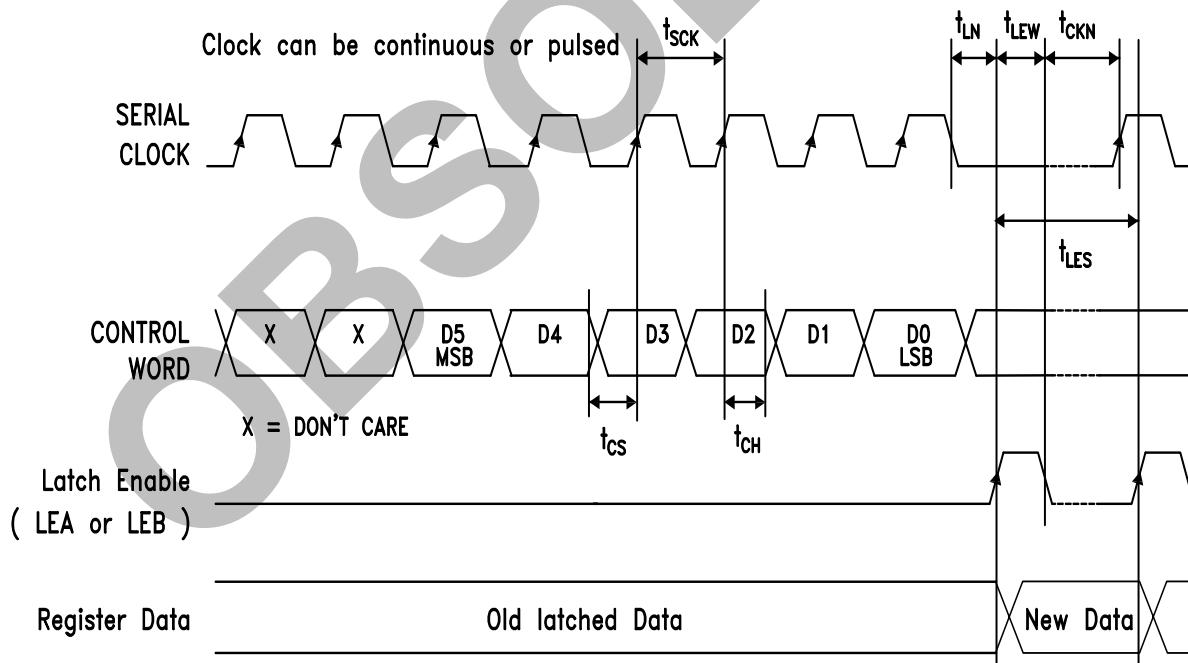
## 0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz

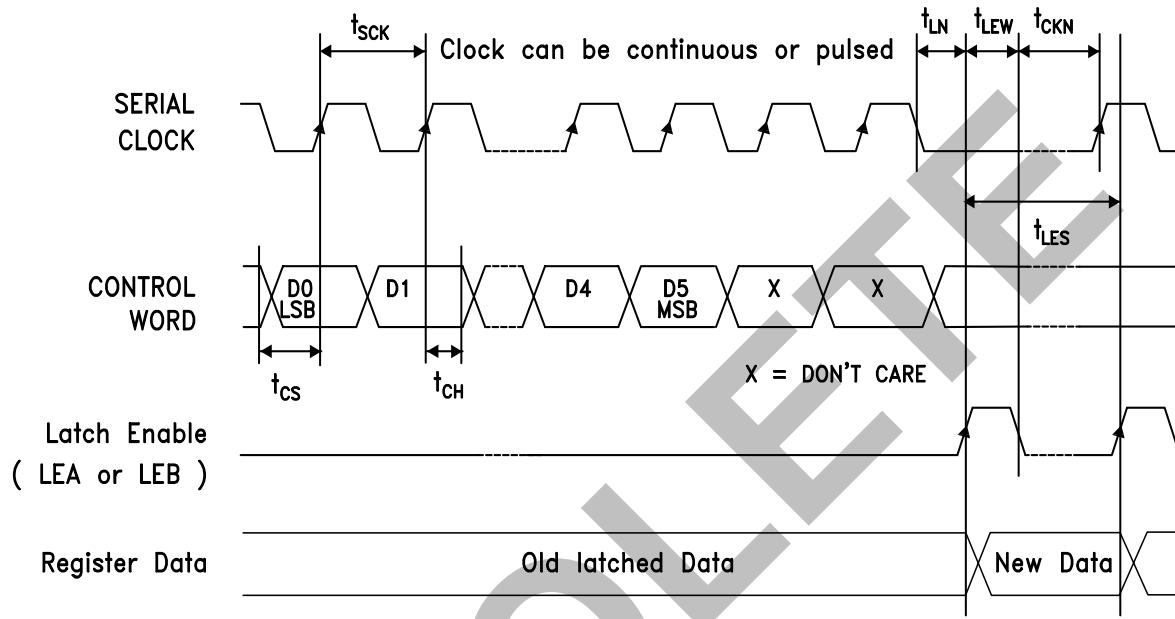
### Serial Control Interface

The HMC743ALP6CE contains a 3-wire SPI compatible digital interface (SERIN, CLK, LEA or LEB and BO) to control 8-bit word serial data. The input (IN) and output (OUT) attenuators can be individually controlled via the latch enable pins. The LEA pin latches the serial 8-bit word to the output attenuator. The LEB pin latches the serial 8-bit word to the input attenuator.

The HMC743ALP6CE can be serially controlled in one of two user-selectable modes: most significant bit first (MSB-first), or least significant bit first (LSB-first). The serial data order is selected by control input BO (bit order select). BO = HIGH sets the MSB-first mode and the BO = LOW sets the LSB-first mode. After the 8-bit serial data is clocked in, the latch enable (LEA,LEB) is pulsed to set the state of attenuator(s) according to the truth table. The input and output attenuators can be controlled independently by applying this procedure separately for each attenuator and using the correct latch enable(LEA or LEB) , or a single control word can set both attenuators by first clocking in the 8-bit serial data word, then applying latch enable pulses to LEA and LEB, either one by one or simultaneously to change the content of the registers.

### MSB-First timing diagram ( BO = HIGH )




**0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz**
**LSB-First timing diagram ( BO = LOW )**

**Truth Table** (for each attenuator)

| Control Voltage Input |      |      |      |      |      | Attenuation |
|-----------------------|------|------|------|------|------|-------------|
| D5                    | D4   | D3   | D2   | D1   | D0   |             |
| High                  | High | High | High | High | High | 0 dB        |
| High                  | High | High | High | High | Low  | -0.5 dB     |
| High                  | High | High | High | Low  | High | -1 dB       |
| High                  | High | High | Low  | High | High | -2 dB       |
| High                  | High | Low  | High | High | High | -4 dB       |
| High                  | Low  | High | High | High | High | -8 dB       |
| Low                   | High | High | High | High | High | -16 dB      |
| Low                   | Low  | Low  | Low  | Low  | Low  | -31.5 dB    |

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.

**PUP Truth Table**

| LE (A and B) | PUP1 | PUP2 | Gain Relative to Max Setting |
|--------------|------|------|------------------------------|
| 0            | 0    | 0    | -63 dB                       |
| 0            | 1    | 1    | 0 dB                         |

**Bit order select**

|    | MSB-first | LSB-first |
|----|-----------|-----------|
| BO | 1         | 0         |

| Parameter                                 | Typ.   |
|---|--------|
| Min. serial period, $t_{SCK}$             | 100 ns |
| Control set-up time, $t_{CS}$             | 20 ns  |
| Control hold-time, $t_{CH}$               | 20 ns  |
| LE setup-time, $t_{LN}$                   | 10 ns  |
| Min. LE pulse width, $t_{LEW}$            | 10 ns  |
| Min LE pulse spacing, $t_{LES}$           | 630 ns |
| Serial clock hold-time from LE, $t_{CKN}$ | 10 ns  |



### ***Absolute Maximum Ratings***

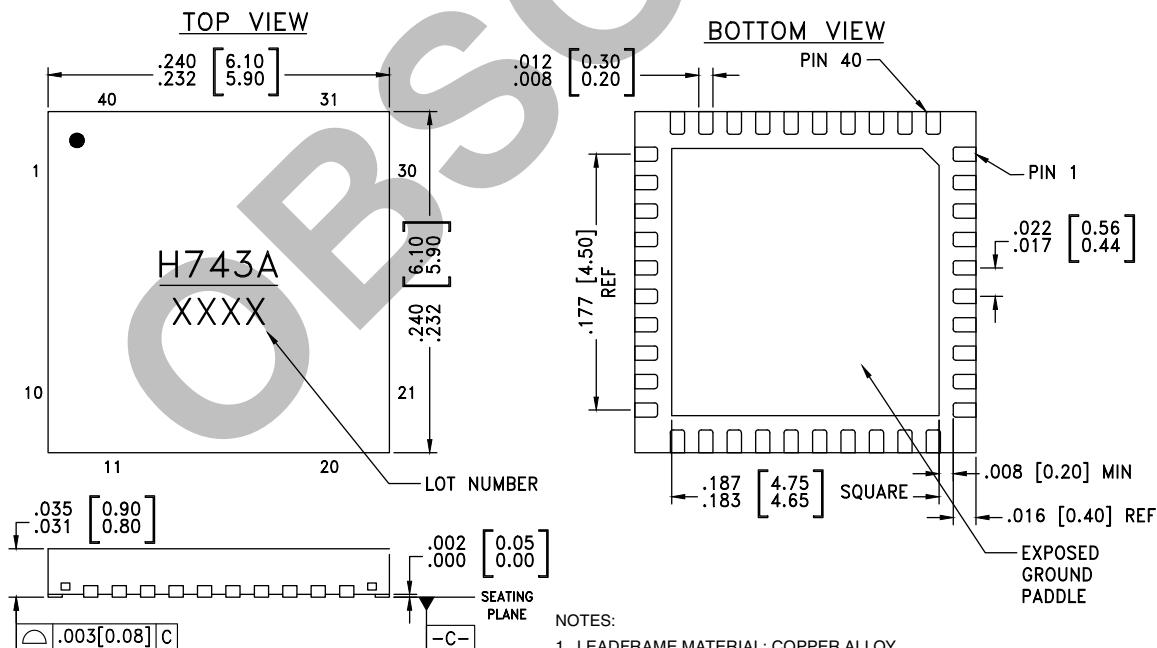
|  |                       |
|--|-----------------------|
| RF Input Power [1]   | 11.5 dBm (T = +85 °C) |
| Digital Inputs (CLK, LEA, LEB, SERIN, PUP1, PUP2 & B0)             | -0.5V to Vdd +0.5V    |
| Bias Voltage (Vdd)   | 5.6V                  |
| Collector Bias Voltage (Vcc)                                       | 5.5V                  |
| Channel Temperature  | 150 °C                |
| Continuous Pdiss (T = 85 °C)<br>(derate 8.4 mW/°C above 85 °C) [2] | 0.546 W               |
| Thermal Resistance [3]   | 119 °C/W              |
| Storage Temperature  | -65 to +150 °C        |
| Operating Temperature  | -40 to +85 °C         |
| ESD Sensitivity (HBM)  | Class 1A              |

[1] The maximum RF input power increases by the same amount the gain is reduced by the input attenuator. The maximum input power at any state is no more than 28 dBm.

[2] This value is the total power dissipation in the amplifier.

[3] This is the thermal resistance for the amplifier.

## ***Outline Drawing***



## **Control Voltage Table**

| State | $V_{dd} = +3V$ , $V_{cc} = +5V$ | $V_{dd} = V_{cc} = +5V$ |
|-------|---------------------------------|-------------------------|
| Low   | 0 to 0.5V @ <1 $\mu A$          | 0 to 0.8V @ <1 $\mu A$  |
| High  | 2 to 3V @ <1 $\mu A$            | 2 to 5V @ <1 $\mu A$    |

## *Bias Voltage*

|     | Voltage (V) | Current (Typ.) (mA) |
|-----|-------------|---------------------|
| Vdd | + 3.0       | 4                   |
|     | + 5.0       | 5                   |
| Vcc | + 5.0       | 82                  |

**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**

NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.  
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

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**0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz**
**Package Information**

| Part Number  | Package Body Material                              | Lead Finish   | MSL Rating          | Package Marking <sup>[2]</sup> |
|--------------|--|---------------|---------------------|--------------------------------|
| HMC743ALP6CE | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 <sup>[1]</sup> | H743A<br>XXXX                  |

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

**Pin Descriptions**

| Pin Number                    | Function           | Description   | Interface Schematic |
|-------------------------------|--------------------|---|---------------------|
| 1                             | RF1                | This pin is DC coupled.<br>An off chip DC blocking capacitor is required.   |                     |
| 38                            | RF6                | RF output and DC bias for the output stage of the amplifier.  |                     |
| 2, 8, 15, 18 - 20, 28, 35, 39 | N/C                | No Connection   |                     |
| 3, 23                         | SEROUT, SERIN      | Data in and out pins  |                     |
| 4, 5                          | PUP1, PUP2         | Controls power up state   |                     |
| 21, 22                        | LEB, LEA           | LEA is the latch enable for the output attenuator.<br>LEB is the latch enable for the input attenuator.                                     |                     |
| 24                            | CLK                | Clock input   |                     |
| 25                            | BO                 | Controls bit order of control word.<br>B0 - High = MSB first<br>B0 - Low = LSB first  |                     |
| 6                             | Vdd                | Supply Voltage  |                     |
| 7, 16, 27, 36                 | RF2, RF3, RF4, RF5 | These pins are DC coupled and matched to 50 Ohms.<br>Blocking capacitors are required. Select value based on lowest frequency of operation. |                     |
| 9 - 14                        | ACG1 - ACG6        | External capacitors to ground are required. Place capacitor as close to pins as possible. See "Components for Selected Frequencies" table.  |                     |
| 17, 26, 37, 40<br>Paddle      | GND                | These pins and the exposed ground paddle must be connected to RF/DC ground.   |                     |
| 29 - 34                       | ACG7 - ACG12       | External capacitors to ground are required. Place capacitor as close to pins as possible. See "Components for Selected Frequencies" table.  |                     |



## 0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz

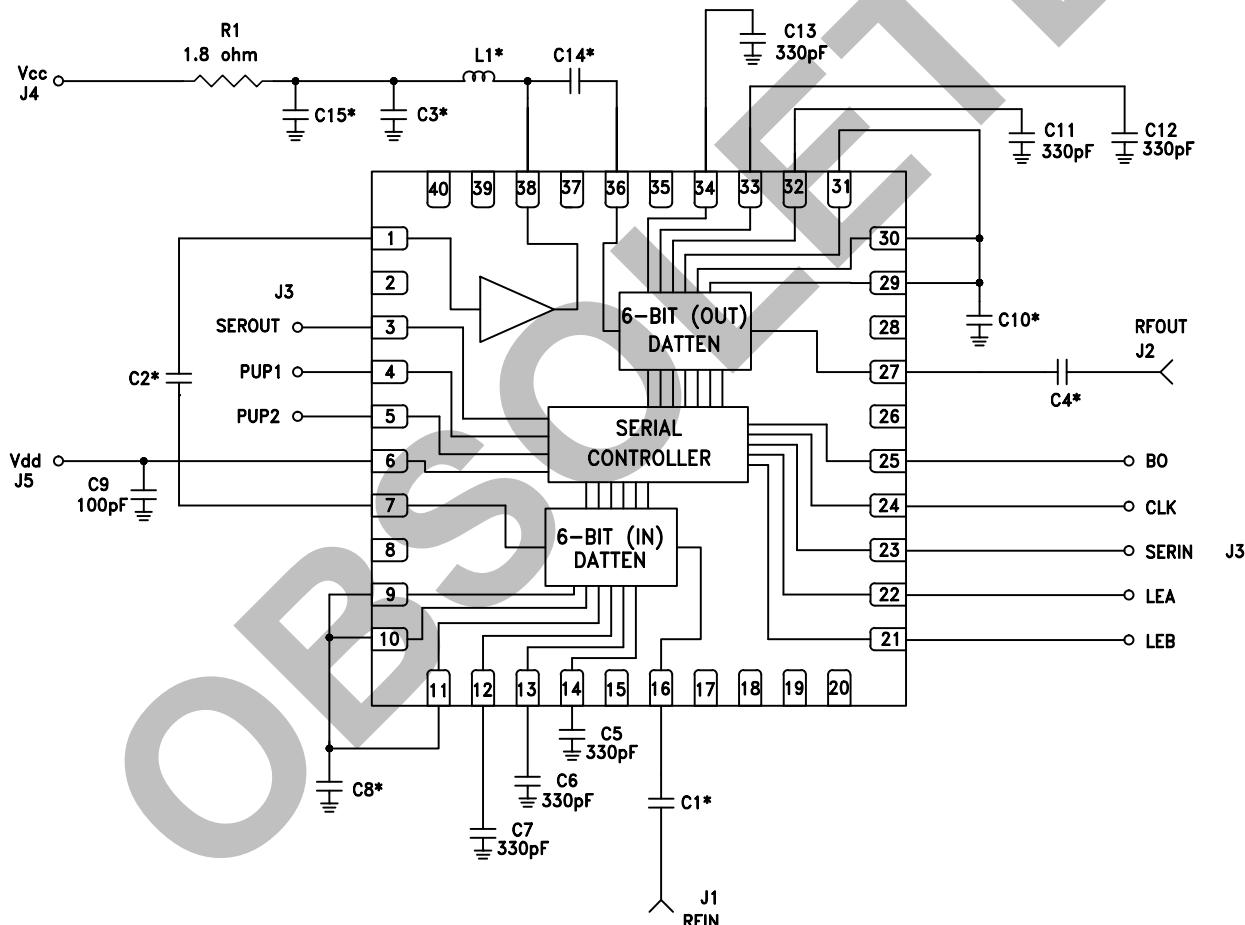
### Power-Up States

The HMC743ALP6CE offers two different power up states, either full attenuation or maximum gain mode. See PUP truth table.

### Power-On Sequence

The ideal power-up sequence is: GND, Vdd, digital inputs, RF inputs. The relative order of the digital inputs are not important as long as they are powered after Vdd / GND

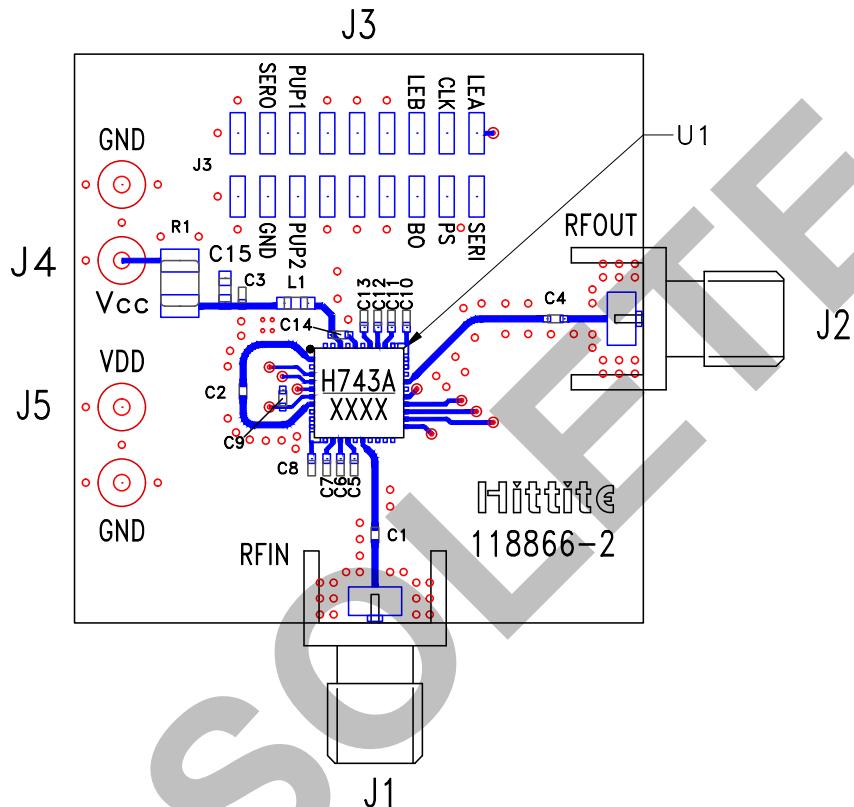
### Application Circuit



### Components for Selected Frequencies \*

| Tuned Frequency      | 70 - 1000 MHz            | 700 - 4000 MHz           |
|----------------------|--------------------------|--------------------------|
| Evaluation PCB       | 124459 - HMC743ALP6C [1] | 124460 - HMC743ALP6C [1] |
| C3 (pF)              | 1000                     | 100                      |
| C1, C2, C4, C14 (pF) | 3300                     | 100                      |
| C8, C10 (pF)         | 100                      | 330                      |
| C15 (pF)             | 2200                     | 1000                     |
| L1 (nH)              | 560                      | 36                       |

[1] Reference this number when ordering complete evaluation PCB.


**0.5 dB LSB GaAs MMIC DUAL 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 4 GHz**
**Evaluation PCB**

**List of Materials for Evaluation <sup>[1]</sup>**

| Item               | Description                          |
|--------------------|--------------------------------------|
| J1, J2             | PCB Mount SMA Connector              |
| J3                 | 18 pos Header, 2mm                   |
| J4, J5             | DC Pin                               |
| C1 - C4            | Capacitor, 0402 Pkg. <sup>[1]</sup>  |
| C5 - C7            | 330 pF Capacitor, 0402 Pkg.          |
| C8, C10            | Capacitor, 0402 Pkg. <sup>[1]</sup>  |
| C9                 | 100 pF Capacitor, 0402 Pkg.          |
| C15                | Capacitor, 0603 Pkg. <sup>[1]</sup>  |
| L1                 | Inductor, 0603 Pkg.                  |
| R1                 | 1.8 Ohm Resistor, 1206 Pkg.          |
| U1                 | HMC743ALP6CE Variable Gain Amplifier |
| PCB <sup>[2]</sup> | 118866 Evaluation PCB                |

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

[1] Please reference Components for Selected Frequencies Table

[2] Circuit Board Material: Arlon 25FR or Rogers 4350